

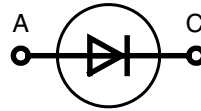
# Fast Recovery Epitaxial Diode (FRED)

$$I_{FAV} = 12 \text{ A}$$

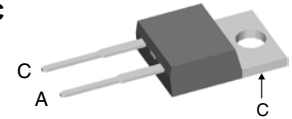
$$V_{RRM} = 1000 \text{ V}$$

$$t_{rr} = 50 \text{ ns}$$

$V_{RSM}$	$V_{RRM}$	Type
V	V	
1000	1000	DSEI 12-10A



TO-220 AC



A = Anode, C = Cathode

Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$	$T_{VJ} = T_{VJM}$	25	A
$I_{FAVM}$ ①	$T_C = 100^\circ\text{C}$ ; rectangular, $d = 0.5$	12	A
$I_{FRM}$	$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$	150	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	75	A
		80	A
	$T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	65	A
		70	A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	28	$\text{A}^2\text{s}$
		27	$\text{A}^2\text{s}$
	$T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	21	$\text{A}^2\text{s}$
		20	$\text{A}^2\text{s}$
$T_{VJ}$		-40...+150	$^\circ\text{C}$
$T_{VJM}$		150	$^\circ\text{C}$
$T_{stg}$		-40...+150	$^\circ\text{C}$
$P_{tot}$	$T_C = 25^\circ\text{C}$	78	W
$M_d$	mounting torque	0.4...0.6	Nm
Weight	typical	2	g

Symbol	Conditions	Characteristic Values		
		typ.	max.	
$I_R$	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$		250	$\mu\text{A}$
	$V_R = 0.8 \cdot V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$		150	$\mu\text{A}$
	$V_R = 0.8 \cdot V_{RRM}$ $T_{VJ} = 125^\circ\text{C}$		4	mA
$V_F$	$I_F = 12 \text{ A}$ $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$		2.1	V
			2.7	V
$V_{T0}$	For power-loss calculations only		1.67	V
$r_T$	$T_{VJ} = T_{VJM}$		33.6	$\text{m}\Omega$
$R_{thJC}$ $R_{thCH}$ $R_{thJA}$			1.6	K/W
		0.5	60	K/W
			60	K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 50 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	50	60	ns
$I_{RM}$	$V_R = 540 \text{ V}$ ; $I_F = 12 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ $L \leq 0.05 \mu\text{H}$ ; $T_{VJ} = 100^\circ\text{C}$	6.5	7.2	A

①  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ .  $V_R = 0.8 \cdot V_{RRM}$ , duty cycle  $d = 0.5$   
Data according to IEC 60747

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## Features

- International standard package JEDEC TO-220 AC
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

## Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

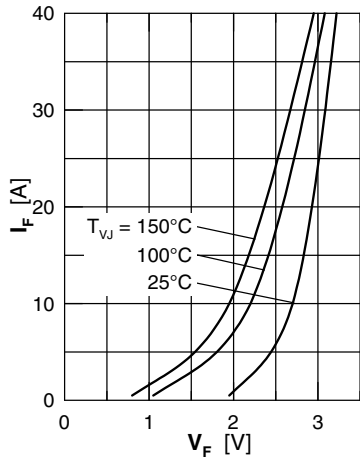


Fig. 1 Forward current versus voltage drop

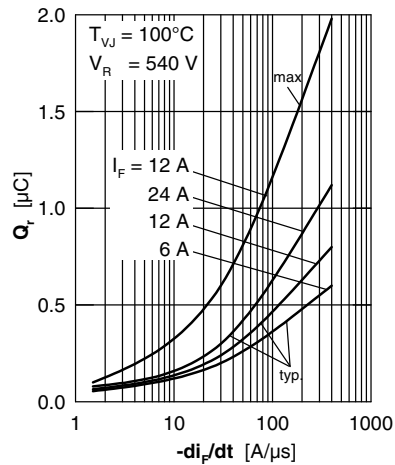


Fig. 2 Recovery charge versus  $-di_F/dt$

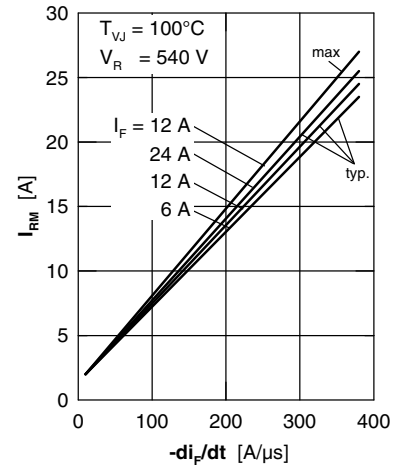


Fig. 3 Peak reverse current versus  $-di_F/dt$

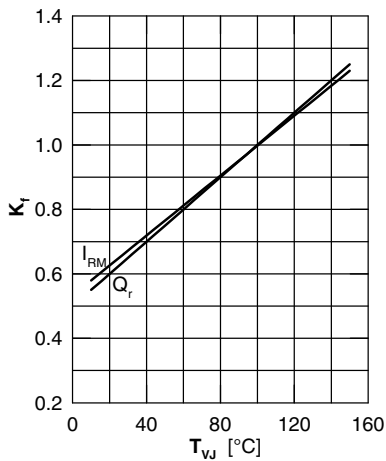


Fig. 4 Dynamic parameters versus junction temperature

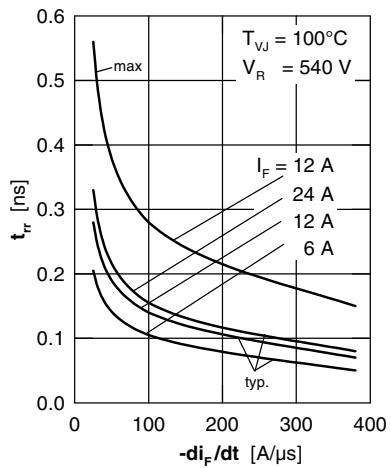


Fig. 5 Recovery time versus  $-di_F/dt$

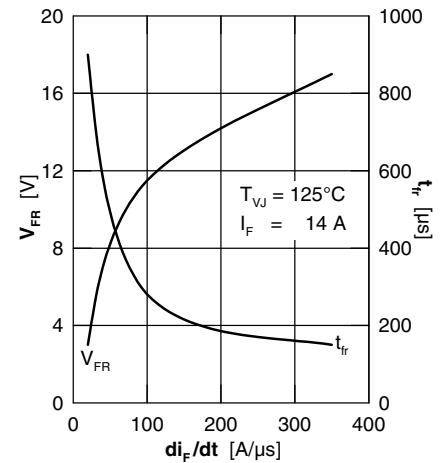


Fig. 6 Peak forward voltage versus  $di_F/dt$

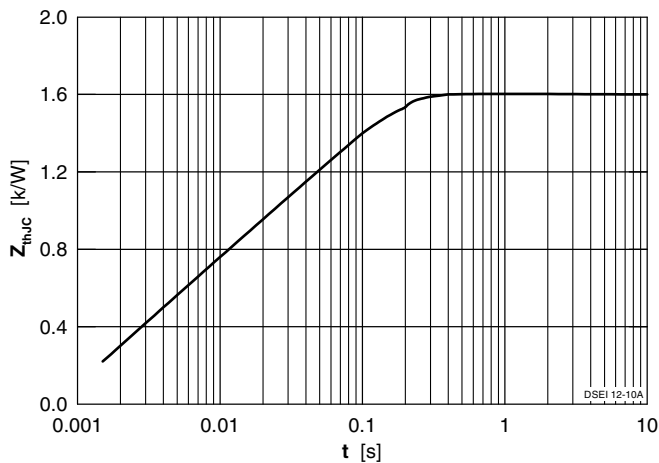


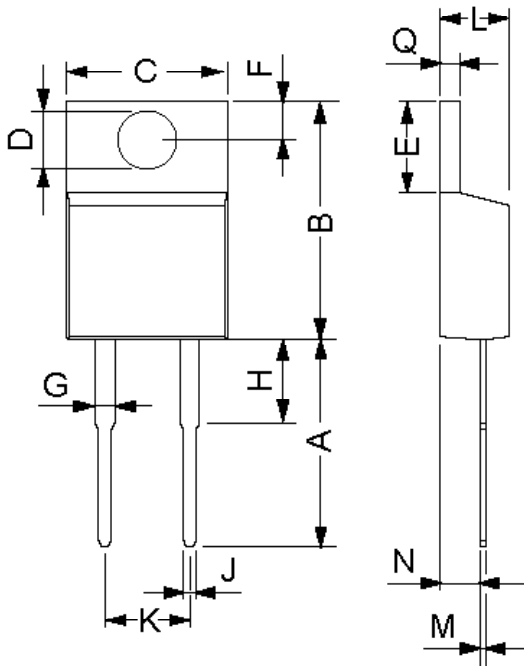
Fig. 7 Transient thermal resistance junction to case

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## Dimensions TO-220 AC



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.7	14.73	0.5	0.58
B	14.23	16.51	0.56	0.65
C	9.66	10.66	0.38	0.42
D	3.54	4.08	0.139	0.161
E	5.85	6.85	2.3	0.42
F	2.54	3.42	0.1	0.135
G	1.15	1.77	0.045	0.07
H	-	6.35	-	0.25
J	0.64	0.89	0.025	0.035
K	4.83	5.33	0.19	0.21
L	3.56	4.82	0.14	0.19
M	0.51	0.76	0.02	0.03
N	2.04	2.49	0.08	0.115
Q	0.64	1.39	0.025	0.055

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